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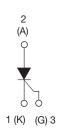


www.vishay.com

Vishay Semiconductors

Thyristor High Voltage, Phase Control SCR, 40 A





TO-247AC

PRODUCT SUMMARY				
Package	TO-247AC			
Diode variation	Single SCR			
I _{T(AV)}	35 A			
V _{DRM} /V _{RRM}	800 V, 1200 V			
V_{TM}	1.45 V			
I _{GT}	150 mA			
TJ	-40 °C to +125 °C			

FEATURES

- Designed and qualified according to JEDEC®-JESD 47
- Low I_{GT} parts available
- 125 °C max. operating junction temperature
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>





ROHS
COMPLIANT
HALOGEN
FREE
Available

APPLICATIONS

 Typical usage is in input rectification crowbar (soft start) and AC switch motor control, UPS, welding and battery charge

DESCRIPTION

The VS-40TPS... high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

MAJOR RATINGS AND CHARACTERISTICS								
PARAMETER	TEST CONDITIONS	VALUES	UNITS					
I _{T(AV)}	Sinusoidal waveform	35	A					
I _{RMS}		55	A					
V _{RRM} /V _{DRM}		800/1200	V					
I _{TSM}		600	А					
V _T	40 A, T _J = 25 °C	1.45	V					
dV/dt		1000	V/µs					
dl/dt		100	A/μs					
T _J		-40 to +125	°C					

VOLTAGE RATINGS									
PART NUMBER	V _{RRM} /V _{DRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA						
VS-40TPS08APbF, VS-40TPS08A-M3	800	900							
VS-40TPS08PbF, VS-40TPS08-M3	800	900	10						
VS-40TPS12APbF, VS-40TPS12A-M3	1200	1300] 10						
VS-40TPS12PbF, VS-40TPS12-M3	1200	1300							



PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average on-state current	I _{T(AV)}	T _C = 79 °C, 180° conduction half sine wa	35			
Maximum continuous RMS on-state current as AC switch	I _{T(RMS)}			55	А	
Maximum peak, one-cycle		10 ms sine pulse, rated $V_{\mbox{\scriptsize RRM}}$ applied		500		
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no voltage reapplied		600		
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	Initial $T_{.1} = T_{.1} \text{ max.}$	1250	A2-	
Maximum i-t for fusing	1-1	10 ms sine pulse, no voltage reapplied		1760	- A ² s	
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied	17 600	A²√s		
Low level value of threshold voltage	V _{T(TO)1}		1.02	V		
High level value of threshold voltage	V _{T(TO)2}	T 405 00	1.23	V		
Low level value of on-state slope resistance	r _{t1}	T _J = 125 °C	9.74			
High level value of on-state slope resistance	r _{t2}			7.50	mΩ	
Maximum peak on-state voltage	V_{TM}	110 A, T _J = 25 °C		1.85	V	
Maximum rate of rise of turned-on current	dI/dt	T _J = 25 °C		100	A/µs	
Maximum holding current	I _H	Anode supply = 6 V, resistive load, initial 7	_J = 1 A, I _T = 25 °C	200		
Maximum latching current	ΙL	Anode supply = 6 V, resistive load, T _J = 2	5 °C	300		
		T _J = 25 °C			mA	
Maximum reverse and direct leakage current	I _{RRM/} I _{DRM}	$T_J = 125 ^{\circ}\text{C}$ $V_R = \text{Rated } V_{RRM}/V_R$	$V_R = Rated V_{RRM}/V_{DRM}$			
Maximum rate of rise of off-state voltage 40TPS12A	-1\	T. T. manifesture literature 20.07 V	500	1//		
Maximum rate of rise of off-state voltage 40TPS12	dV/dt	$T_J = T_J$ maximum, linear to 80 % V_{DRM} , F	1000	- V/μs		

TRIGGERING					
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS		
Maximum peak gate power	P _{GM}			10	W
Maximum average gate power	P _{G(AV)}			2.5	VV
Maximum peak gate current	I _{GM}			2.5	Α
Maximum peak negative gate voltage	- V _{GM}			10	V
		T _J = - 40 °C		4.0	V
Maximum required DC gate voltage to trigger	V _{GT}	T _J = 25 °C	Anode supply = 6 V resistive load	2.5	
		T _J = 125 °C	resistive load	1.7	
		T _J = - 40 °C		270	mA
Marian and in 180 and a small a life and	I _{GT}	T _J = 25 °C	Anode supply = 6 V resistive load	150	
Maximum required DC gate current to trigger		T _J = 125 °C	Tesistive load	80	
		$T_J = 25$ °C, for 40TPS08API	40		
Maximum DC gate voltage not to trigger for 40TPS12	V_{GD}			0.25	V
Maximum DC gate current not to trigger for 40TPS12	I _{GD}	$T_J = 125 ^{\circ}\text{C}, V_{DRM} = \text{Rated}$	6	mA	
Maximum DC gate voltage not to trigger for 40TPS12A	V_{GD}	T = 125 °C V = Poted	0.15	V	
Maximum DC gate current not to trigger for 40TPS12A	I _{GD}	1j = 125 C, v _{DRM} = Hated	T _J = 125 °C, V _{DRM} = Rated value		

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THERMAL AND MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range)	T_J, T_{Stg}		-40 to +125	°C			
Maximum thermal resistance, junction to case		R_{thJC}	DC operation	0.6				
Maximum thermal resistance, junction to ambient		R_{thJA}	DC operation	40	°C/W			
Maximum thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.2				
Approximate weight				6	g			
Approximate weight				0.21	OZ.			
Manustinantanan	minimum			6 (5)	kgf · cm			
Mounting torque ——	maximum			12 (10)	(lbf \cdot in)			
				40TP	S08A			
Manding desire			O TO 04740	40TPS12A				
Marking device			Case style TO-247AC	40TPS08				
				40TPS12				

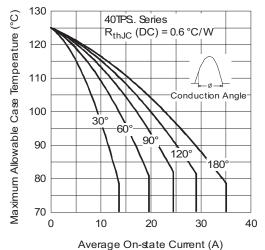


Fig. 1 - Current Rating Characteristics

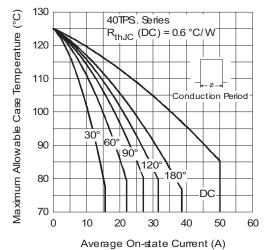


Fig. 2 - Current Rating Characteristics

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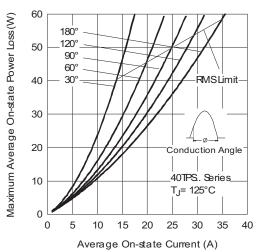
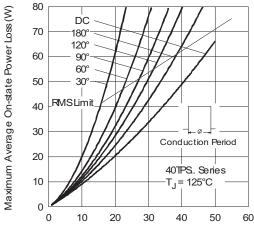
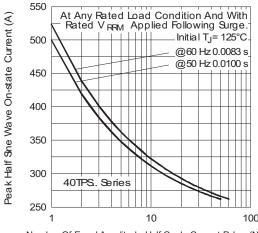


Fig. 3 - On-State Power Loss Characteristics



Average On-state Current (A)
Fig. 4 - On-State Power Loss Characteristics



Number Of Equal Amplitude Half Cycle Current Pulses (N) Fig. 5 - Maximum Non-Repetitive Surge Current

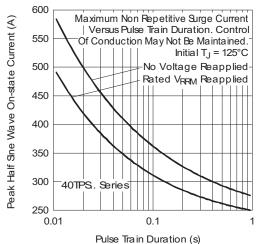


Fig. 6 - Maximum Non-Repetitive Surge Current

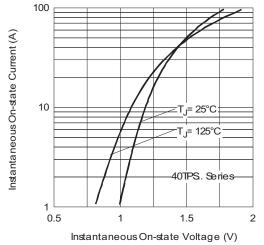


Fig. 7 - On-State Voltage Drop Characteristics

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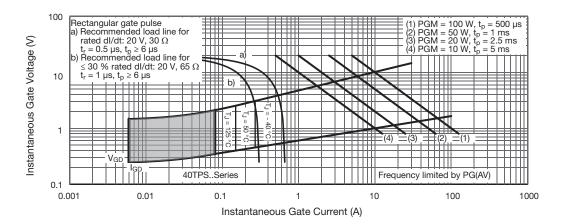


Fig. 8 - Gate Characteristics

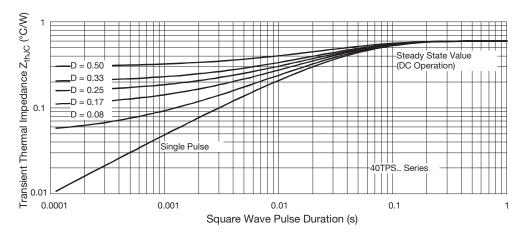
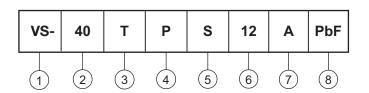


Fig. 9 - Thermal Impedance Z_{thJC} Characteristics

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (40 = 40 A)

Circuit configuration:

T = Thyristor

4 - Package:

P = TO-247

5 - Type of silicon:

S = Standard recovery rectifier

08 = 800 V 12 = 1200 V

6 - Voltage ratings

• A = Low Igt selection 40 mA maximum

• None = Standard Igt selection

8 - Environmental digit:

PbF = Lead (Pb)-free and RoHS compliant

-M3 = Halogen-free, RoHS compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-40TPS08APbF	25	500	Antistatic plastic tubes						
VS-40TPS08A-M3	25	500	Antistatic plastic tubes						
VS-40TPS08PbF	25	500	Antistatic plastic tubes						
VS-40TPS08-M3	25	500	Antistatic plastic tubes						
VS-40TPS12APbF	25	500	Antistatic plastic tubes						
VS-40TPS12A-M3	25	500	Antistatic plastic tubes						
VS-40TPS12PbF	25	500	Antistatic plastic tubes						
VS-40TPS12-M3	25	500	Antistatic plastic tubes						

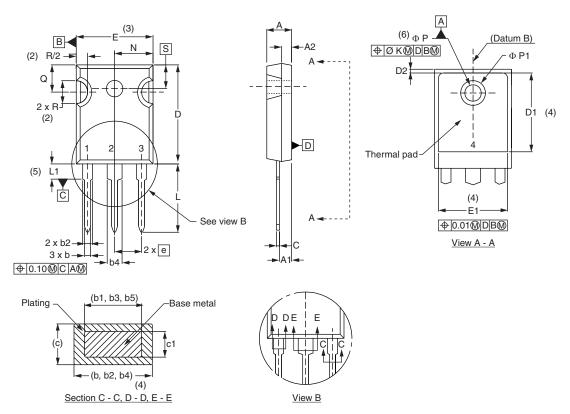
LINKS TO RELATED DOCUMENTS							
Dimensions <u>www.vishay.com/doc?95542</u>							
Dout moulting information	TO-247AC PbF	www.vishay.com/doc?95226					
Part marking information	TO-247AC-M3	www.vishay.com/doc?95007					



Vishay Semiconductors

TO-247 - 50 mils L/F

DIMENSIONS in millimeters and inches



SYMBOL MILLIMETER		MILLIMETERS INCHES		INCHES		NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209			D2	0.51	1.35	0.020	0.053	
A1	2.21	2.59	0.087	0.102			Е	15.29	15.87	0.602	0.625	3
A2	1.17	1.37	0.046	0.054			E1	13.46	-	0.53	ı	
b	0.99	1.40	0.039	0.055			е	5.46	BSC	0.215	BSC	
b1	0.99	1.35	0.039	0.053			ØK	0.2	254	0.0	10	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.34	0.065	0.092			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			Ν	7.62	BSC	0	.3	
b5	2.59	3.38	0.102	0.133			ØΡ	3.56	3.66	0.14	0.144	
С	0.38	0.89	0.015	0.035			Ø P1	1	7.39	1	0.291	
c1	0.38	0.84	0.015	0.033			Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3		R	4.52	5.49	0.178	0.216	
D1	13.08	-	0.515	-	4		S	5.51	BSC	0.217	BSC	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension c and Q



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